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| **學期** | **學年度 學期** |
| **日期** | **\_\_\_ 歹 年 月 日** |

國立臺北科技大學 化學工程與生物科技系(博士班) 論文發表檢核表

**National Taipei University of Technology, Department of Chemical Engineering and Biotechnology**

**Ph.D. Program Publication Checklist**

|  |  |  |  |  |  |  |  |  |  |  |  |
| --- | --- | --- | --- | --- | --- | --- | --- | --- | --- | --- | --- |
| **組別**  **Group** | | **學號**  **Student I.D.** | | **姓名**  **Name of Applicant** | | | **申請日期**  **Application date** | | | | |
| □Chemical Engineering  □Biochemical and Biomedical Engineering | |  | | (中文) | | | 年 月 日  Year Month Day | | | | |
| (英文) | | |
| **資格考科目及成績**  **Ph.D. Candidate Qualification Examination** | | 科目 Subjects | | 成績 Score | 已於 學年度第 學期通過博士學位候選人資格考核  註1：通過2科筆試  註2：通過1科筆試+1科抵免  註3：通過1科筆試+1篇SCI論文(除指導教授外為第一作者) | | | | | | |
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| **修習學分數**  **Credits** | | **必修(A)** | **18** | | 該生已取得學分(a) | | 必修 |  | | 選修 |  |
| **選修(B)** | **21** | | 博士論文學分(b) | |  | | | | |
| **最低畢業學分(A+B)** | **39** | | 該生畢業學分(a+b) | |  | | | | |
| **論文檢核 Publication Checklist** | |  | | | | | | | | | |
| **序號**  **No.** | **論文名稱**  **Article title** | **論文出處（含期刊名稱、期(卷）數及頁碼）**  **Source (including Journal name, volume no., page no.)** | | |  | | --- | | **發表日期**  **Date published** | | **作者排名**  **（請填阿拉伯數字）**  **Author ranking** | | **論文類別**  **（請勾選）**  **Type of publication** | | | | |
| 1 | Vanadium carbide and nitrogen-doped graphene nanosheets based layered architecture for electrochemical evaluation of clioquinol detection and energy storage application | 期刊名稱: Electrochimica Acta  期:2022,卷:408,頁碼:139930 | | 18 January 2022 |  | 含指導教授  Advisor included | □  □  □  □ | | SCI  EI  Other Periodicals  Conferences | | |
| 1 | 不含指導教授  Advisor not included |
| 2 |  |  | |  |  | 含指導教授  Advisor included | □  □  □  □ | | SCI  EI  Other Periodicals  Conferences | | |
|  | 不含指導教授  Advisor not included |
| 3 |  |  | |  |  | 含指導教授  Advisor included | □  □  □  □ | | SCI  EI  Other Periodicals  Conferences | | |
|  | 不含指導教授  Advisor not included |
| **發明專利檢核 Invention Patents** | |  | | | | | | | | | |
| **序號**  **No.** | **專利名稱**  **Title of the invention** | **申請人**  **Applicant** | | |  | | --- | | **發明人**  **Inventor** | | **申請案號**  **Appl. No.** | | **申請日期**  **Filed Date** | | | | |
| 1 |  |  | |  |  | |  | | | | |
| 2 |  |  | |  |  | |  | | | | |

注意事項：

1. 博士班學生應以國立臺北科技大學化學工程與生物科技系發表之論文，始得填寫於本表。
2. 論文序號依發表日期先後順序，以阿拉伯數字填寫，愈晚發表者愈先填寫。
3. 已接受但未印出之論文，請於「論文出處」中載明，於「發表日期」中填寫被接受日期，並於附件中檢附接受函。
4. 每篇論文均需檢附與正本相同之影本為附件，依序列於本表後方，並以隔頁紙分隔。
5. 學術導向博士班學生須有三篇論文在國內外重要學術會議或期刊以英文發表（含已被接受者），除指導教授外，為第一作者。三篇英文論文中須有一篇以上在SCI期刊發表，學術會議論文發表除摘要外應另檢附全文或口頭發表或海報發表的佐證檔案資料。
6. 技術導向博士班學生須有一篇以上以英文發表在SCI或EI期刊（含已被接受者），除指導教授外，為第一作者。且至少以本校名義申請獲得二件與論文有關之發明專利（除指導教授外，為第一發明人），並經系所學術委員會審查通過。
7. 申請人需依實際資料確實詳填本表，並具結簽名，若有不實造假之處，依相關規定辦理。
8. 本表不敷使用時得自行加印。

Notes:

1. A Doctoral student has to be the first author of publications except the advisor, and the the organization must include TAIPEI TECH.
2. Number your publications chronologically starting from the most recent.
3. If the paper has been accepted but not yet published, fill in the date accepted instead of publication date and then attach a copy of the letter of acceptance.
4. Print out and bind each article properly as attachment.
5. A doctoral student of academic orientation should publish at least 3 articles in English and at least one in these three publications should be in distinguished SCI journals. If the article is written by more than one author other than the advisor, the first author must be the applying Ph.D. candidate. Please provide the whole article or proof of publication along with the abstract.
6. A doctoral student of technical orientation should publish at least one article in distinguished SCI or EI journals. If the article is written by more than one author other than the advisor, the first author must be the applying Ph.D. candidate. Besides, the student should file at least 2 invention patent applications relating with the doctoral dissertation which should be reviewed and accepted by the committee. If the patents are invented by more than one inventor other than the advisor, the first inventor must be the applying Ph.D. candidate, and the applicant must include TAIPEI TECH.
7. An applicant should declare that all of the information made above and documents of proof submitted are true. In case of any false information, the applicant will bear relevant liabilities and consequences.

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| 審查委員（簽章）  Committee Signature  審查日期：  Date reviewed Year/Month/Day |  |  |  |  |
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|  | 申請人  Applicant | 指導教授  Advisor | 系所主管  Department Chair |
| 簽章  Signature |  |  |  |
| 日期  Date Year/Month/Day |  |  |  |